General purpose transistor (isolated transistor and diode) QSL9

A 2SB1709 and a RB461F are housed independently in a TSMT5 package.

Applications

DC / DC converter Motor driver

● Features

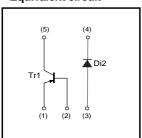
1) Tr : Low Vce(sat) Di : Low Vr

2) Small package

●Structure

Silicon epitaxial planar transistor Schottky barrier diode

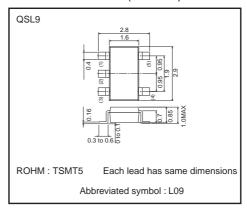
●Equivalent circuit



Packaging specifications

Туре	QSL9
Package	TSMT5
Marking	L09
Code	TR
Basic ordering unit(pieces)	3000

●External dimensions (Unit : mm)



● Absolute maximum ratings (Ta=25°C)

Tr1

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	-15	V
Collector-emitter voltage	Vceo	-12	V
Emitter-base voltage	Vево	-6	V
Collector current	Ic	-1.5	Α
	Іср	-3	A *1
Power dissipation	Pc	0.9	W/ELEMENT*2
Junction temperature	Tj	150	°C
Range of storage temperature	Tstg	-40 to +125	°C

Di2

Parameter	Symbol	Limits	Unit
Peak reverse voltage	VRM	25	V
Reverse voltage (DC)	VR	20	V
Average rectified forward current	lF	700	ma
Forward current surge peak (60Hz, 1∞)	Iгsм	3	А
Power dissipation	Po	0.7	W/ELEMENT *
Junction temperature	То	125	°C
Range of storage temperature	Tstg	-40 to +125	°C

^{*} Mounted on a 25mm×25mm×10.8mm ceramic substrate.

● Tr1 & Di2

Parameter	Symbol	Limits	Unit
Total power dissipation	Do	0.5	W/TOTAL *1
	Po	1.25	W/TOTAL *2

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVceo	-12	_	_	V	Ic=-1mA
Collector-base breakdown voltage	ВУсво	-15	-	_	V	Ic=-10μA
Emitter-base breakdown voltage	ВУЕВО	-6	-	_	V	I _E =-10μA
Collector cut-off current	Ісво	_	-	-100	nA	VcB=-15V
Emitter cut-off current	Ієво	_	-	-100	nA	V _{EB} =-6V
Collector-emitter saturation voltage	VCE(sat)	_	-110	-200	mV	Ic=-500mA, Iв=-25mA
DC current gain	hfe	270	_	680	_	Vce=-2V, Ic=-200mA
Transition frequency	f⊤	_	400	_	MHz	Vce=-2V, Ie=200mA, f=100MHz
Collector output capacitance	Cob	_	12	_	pF	Vcb=-10V, IE=0mA, f=1MHz

Di2

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	_	_	490	mV	I _F =700mA
Reverse current	l _R	_	_	200	μΑ	V _R =20V
Reverse recovery time	trr	_	9	_	ns	IF=IR=100mA,Irr=0.1IR



^{*1} Single pulse, Pw=1ms.
*2 Mounted on a 25mm×25mm×10.8mm ceramic substrate.
*3 Each terminal mounted on a recommended.

^{*1} Each terminal mounted on a recommended. *2 Mounted on a 25mm×25mm×¹0.8mm seramic substrate.

Electrical characteristic curves

Tr1

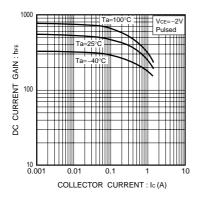


Fig.1 DC current gain vs. collector current

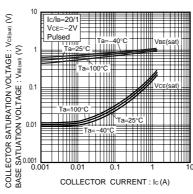


Fig.2 Base-emitter saturation voltage vs. collector current

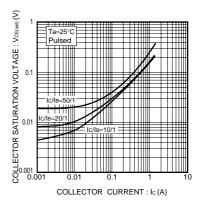


Fig.3 Collector-emitter saturation voltage vs. collector current

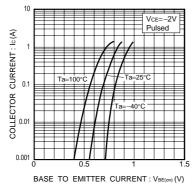


Fig.4 Grounded emitter propagation characteristics

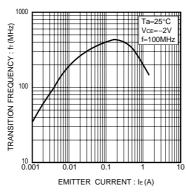


Fig.5 Gain bandwidth product vs. emitter current

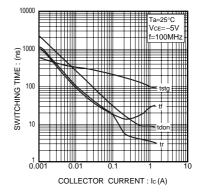


Fig.6 Switching time

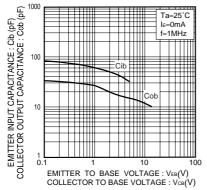
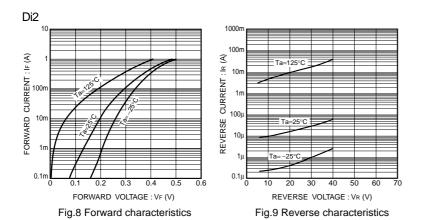


Fig.7 Collector output capacitance vs. collector-base voltage Emitter input capacitance vs. emitter-base voltage



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